

Title (en)
SEMICONDUCTOR WAFER SURFACE PROTECTING SHEET AND SEMICONDUCTOR WAFER PROTECTING METHOD USING SUCH PROTECTING SHEET

Title (de)
HALBLEITERWAFEROBERFLÄCHENSCHUTZFILM UND HALBLEITERWAFERSCHUTZVERFAHREN MIT EINEM SOLCHEN SCHUTZFILM

Title (fr)
FEUILLE DE PROTECTION DE LA SURFACE D'UNE TRANCHE A SEMI-CONDUCTEUR ET PROCEDE DE PROTECTION DE TRANCHE A SEMI-CONDUCTEUR EMPLOYANT LADITE FEUILLE

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Application
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Priority
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Abstract (en)
A semiconductor wafer surface protection sheet which can prevent breakage of a semiconductor wafer even when a circuit-formed surface of the semiconductor wafer has a significant unevenness, and a method for protecting the semiconductor wafer by using such protection sheet. The semiconductor wafer surface protection sheet includes at least one resin layer (A) satisfying a relationship of $G'(60) / G'(25) < 0.1$, where $G'(25)$ is a storage elastic modulus at 25°C, and $G'(60)$ is a storage elastic modulus at 60°C The semiconductor wafer protecting method using such sheet is also provided.

IPC 8 full level
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